

# RJK6011DJE

600V - 0.1A - MOS FET  
High Speed Power Switching

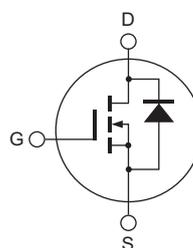
R07DS1153EJ0400  
(Previous: REJ03G1577-0300)  
Rev.4.00  
Jan 28, 2014

## Features

- Low on-resistance  
 $R_{DS(on)} = 35 \Omega$  typ. (at  $I_D = 0.05$  A,  $V_{GS} = 10$  V,  $T_a = 25^\circ\text{C}$ )
- Low drive current
- High density mounting

## Outline

RENESAS Package code: PRSS0003DC-A  
(Package name: TO-92 Mod)



1. Source
2. Drain
3. Gate

## Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	600	V
Gate to source voltage	$V_{GSS}$	$\pm 30$	V
Drain current	$I_D$	0.1	A
Drain peak current	$I_{D(pulse)}$ <sup>Note1</sup>	0.4	A
Body-drain diode reverse drain current	$I_{DR}$	0.1	A
Body-drain diode reverse drain peak current	$I_{DR(pulse)}$ <sup>Note1</sup>	0.4	A
Channel dissipation	Pch	0.9	W
Channel to ambient thermal impedance	$\theta_{ch-a}$	139	$^\circ\text{C/W}$
Channel temperature	Tch	150	$^\circ\text{C}$
Storage temperature	Tstg	-55 to +150	$^\circ\text{C}$

Notes: 1.  $PW \leq 10 \mu\text{s}$ , duty cycle  $\leq 1\%$

## Electrical Characteristics

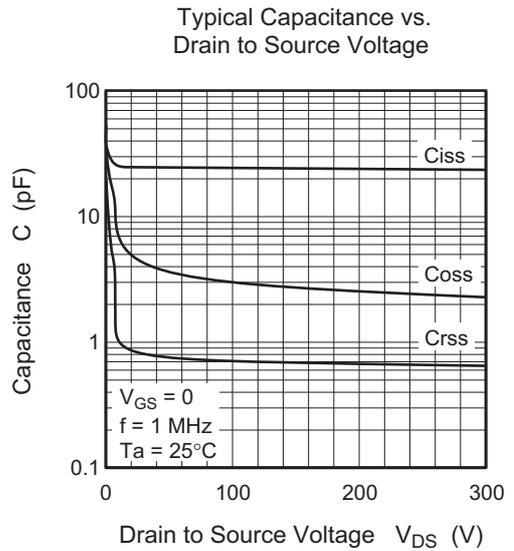
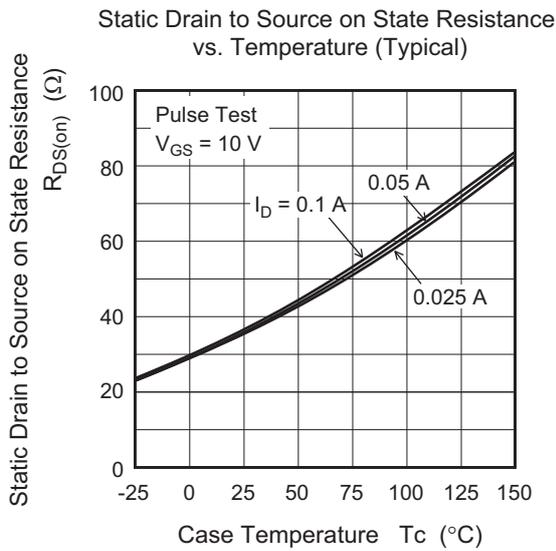
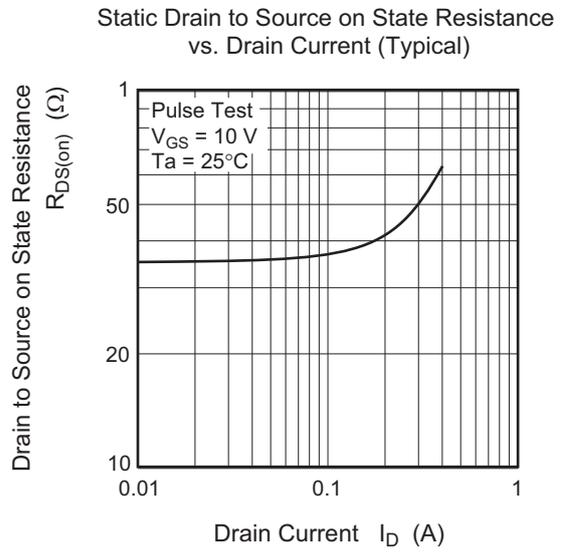
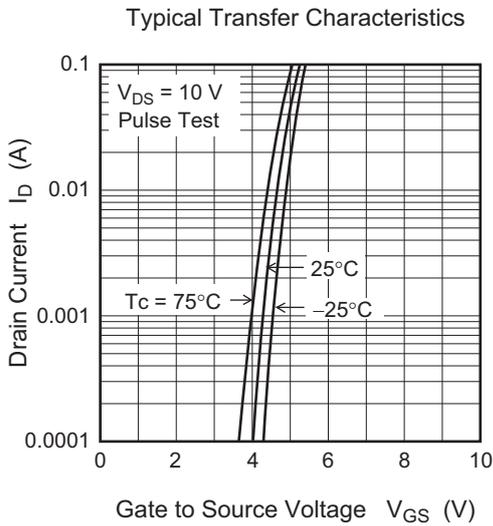
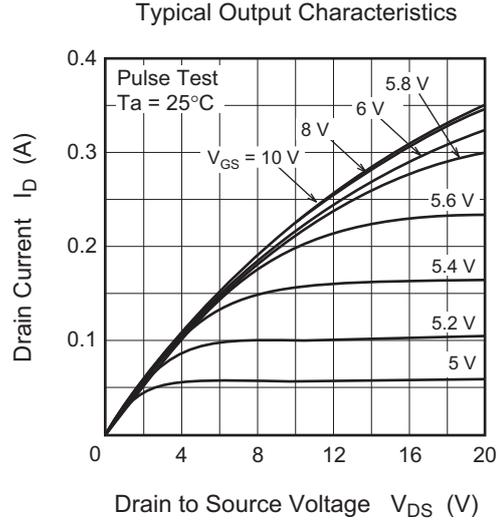
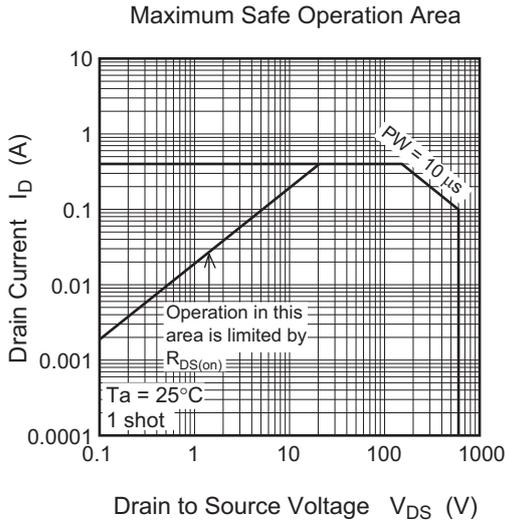
(Ta = 25°C)

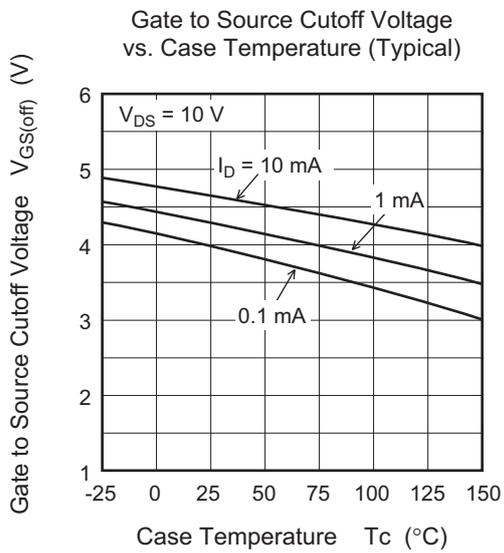
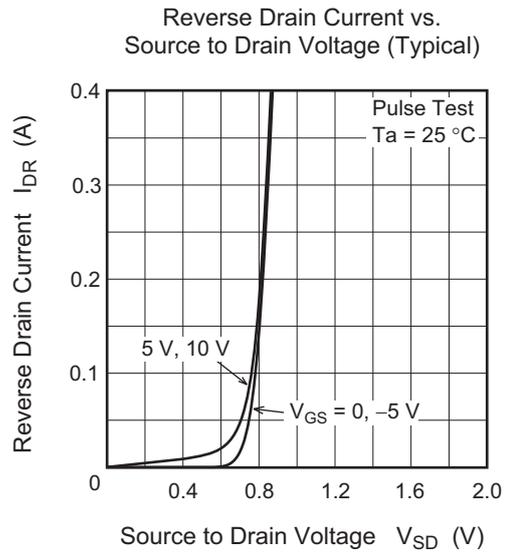
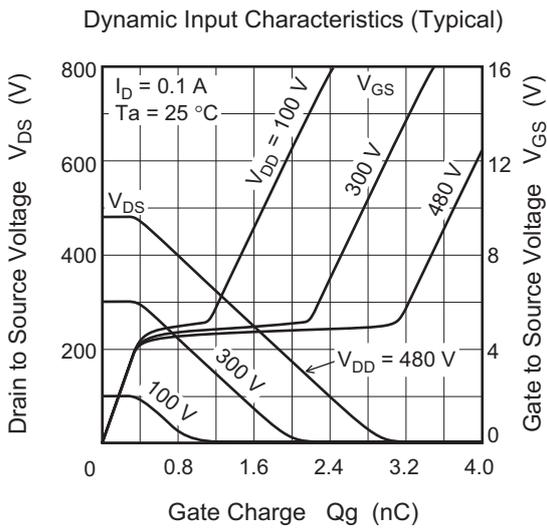
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	—	—	V	$I_D = 10 \text{ mA}$ , $V_{GS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 600 \text{ V}$ , $V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	—	—	$\pm 0.1$	$\mu\text{A}$	$V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3	—	5	V	$V_{DS} = 10 \text{ V}$ , $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	35	52	$\Omega$	$I_D = 0.05 \text{ A}$ , $V_{GS} = 10 \text{ V}$ <sup>Note2</sup>
Input capacitance	$C_{iss}$	—	25	—	pF	$V_{DS} = 25 \text{ V}$
Output capacitance	$C_{oss}$	—	4.7	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	$C_{rss}$	—	0.9	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	33	—	ns	$I_D = 0.05 \text{ A}$
Rise time	$t_r$	—	16	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	54	—	ns	$R_L = 6000 \Omega$
Fall time	$t_f$	—	300	—	ns	$R_g = 10 \Omega$
Total gate charge	$Q_g$	—	3.7	—	nC	$V_{DD} = 480 \text{ V}$
Gate to source charge	$Q_{gs}$	—	0.4	—	nC	$V_{GS} = 10 \text{ V}$
Gate to drain charge	$Q_{gd}$	—	2.7	—	nC	$I_D = 0.1 \text{ A}$
Body-drain diode forward voltage	$V_{DF}$	—	0.80	1.35	V	$I_F = 0.1 \text{ A}$ , $V_{GS} = 0$ <sup>Note2</sup>

Notes: 2. Pulse test

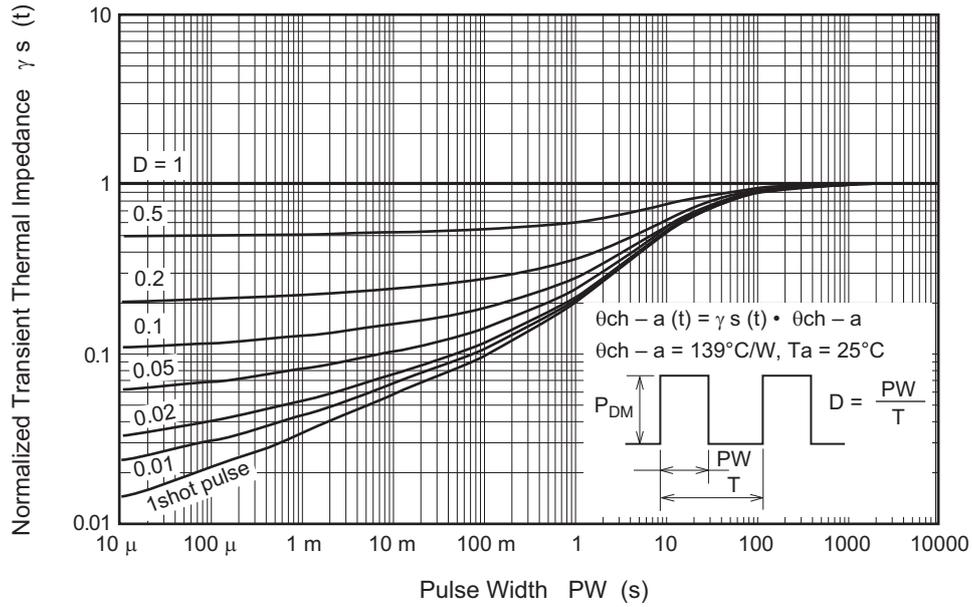
3. Since this device is equipped with high voltage FET chip ( $V_{DSS} \geq 600 \text{ V}$ ), high voltage may be supplied. Therefore, please be sure to confirm about Electric discharge between Drain terminal and other terminal.
4. This device is sensitive to electrostatic discharge.  
It is recommended to adopt appropriate cautions when handling this product.

### Main Characteristics

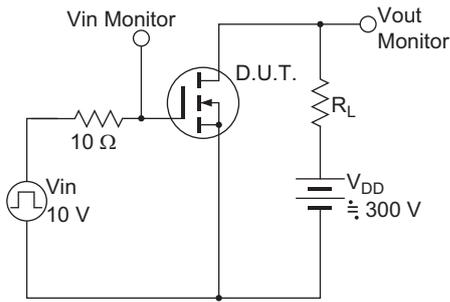




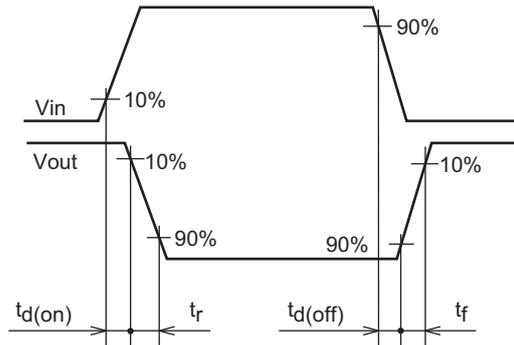
Normalized Transient Thermal Impedance vs. Pulse Width



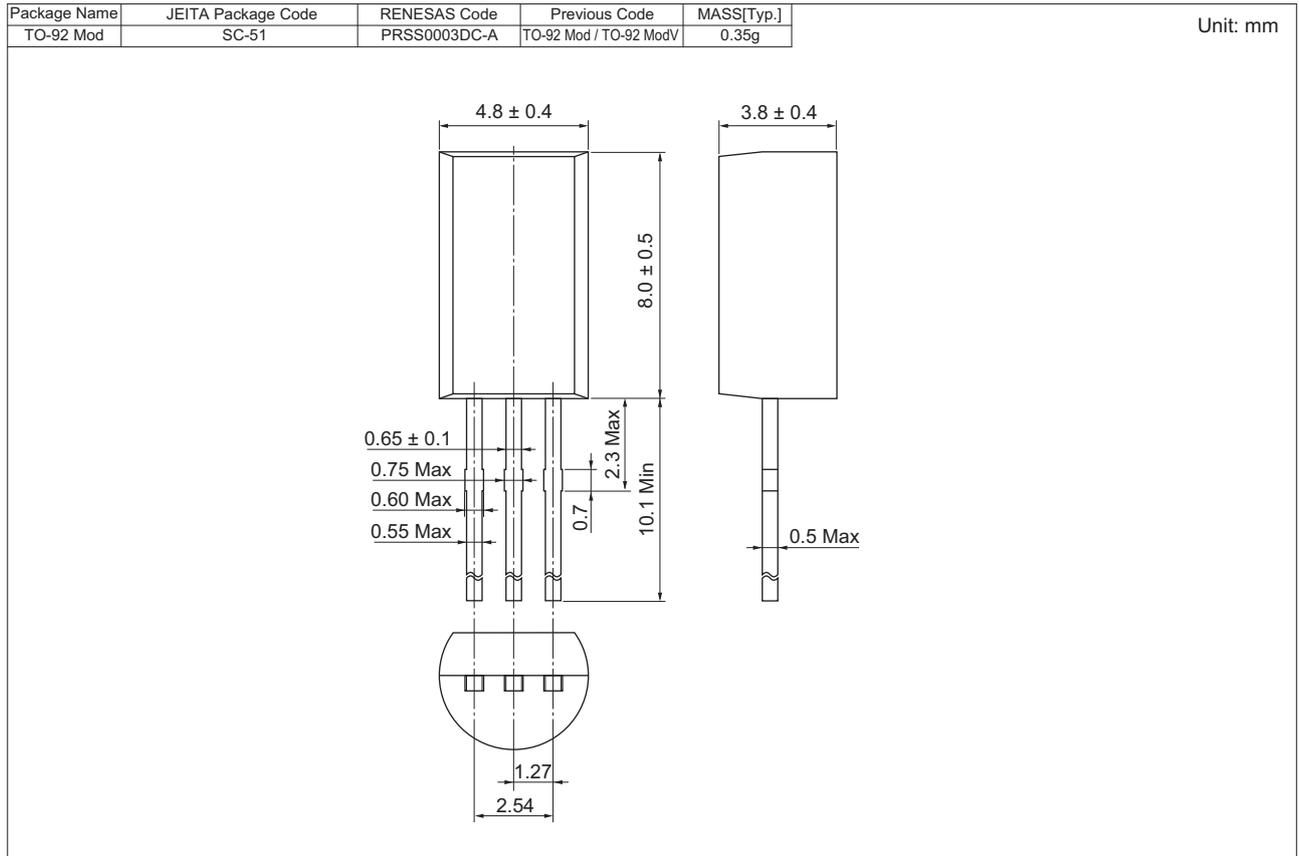
Switching Time Test Circuit



Waveform



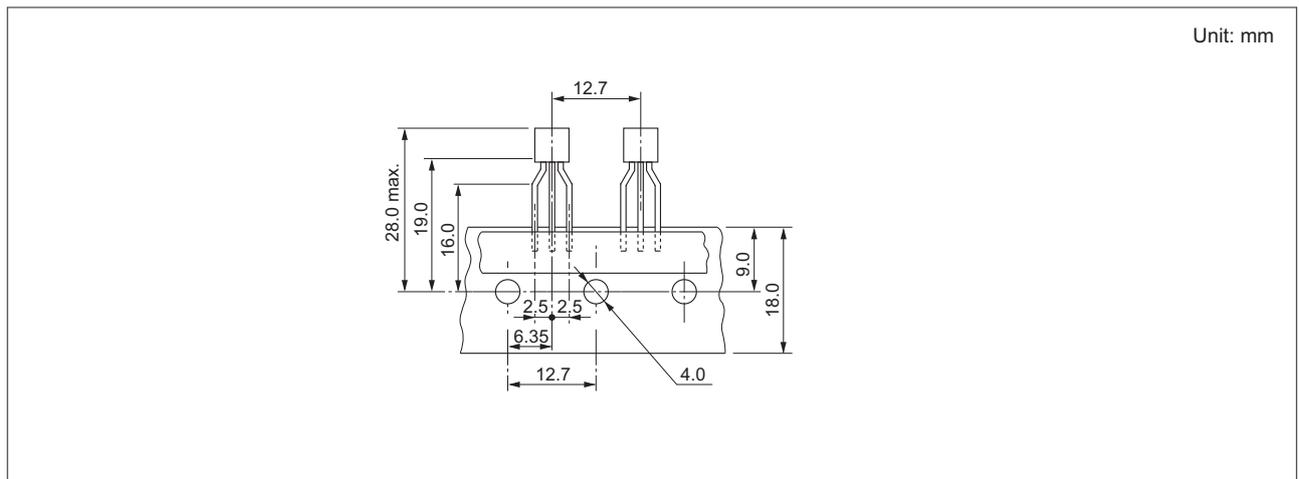
### Package Dimensions



### Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK6011DJE-00#Z0	2500 pcs	Hold Box, Radial Taping

Note: Leads is forming applied as following figure.



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